Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-190-5937

| Gla | ass   |
|-----|---|
| ٥v  | verall Length:                                      |
| 0.3 | 375 inches  |
| Те  | rminal Length:                                      |
| 1.0 | 000 inches  |
| ٥v  | verall Diameter:                                    |
| 0.2 | 200 inches  |
| Mc  | ounting Method:                                     |
| Те  | rminal  |
| Fe  | atures Provided:                                    |
| He  | ermetically sealed case                             |
| Se  | miconductor Material:                               |
| Sil | icon  |
| Vo  | Itage Rating In Volts Per Characteristic:           |
| 1.0 | ) forward voltage, dc                               |
| Cu  | Irrent Rating Per Characteristic:                   |
| 3.0 | 00 amperes forward current, dc                      |
| Ма  | aximum Operating Tempurature Per Measurement Point: |
| 17  | 5.0 degrees celsius ambient air                     |
| Те  | rminal Type And Quantity:                           |
| 2ι  | uninsulated wire lead                               |
| Sh  | nelf Life:  |
| N/a | a   |
| Un  | nit Of Measure:                                     |
|     |   |
| De  | emilitarization:                                    |
| No  |   |
| Fii | g:  |
| A1  | 10a0  |